

20 V, single P-channel Trench MOSFET 30 November 2012

Product data sheet

1. Product profile

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1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- 2.4 kV ESD protected
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Tin-plated 100 % solderable side pads for optical solder inspection

1.3 Applications

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- Charging switch for portable devices
- DC-to-DC converters
- Power management in battery-driven portable devices
- Hard disk and computing power management

1.4 Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-10.3	А
Static charact	eristics	·		·			
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -7.2 A; T _j = 25 °C		-	19	23.5	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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2. Pinning information

Table 2.	Pinning	information			
Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	D	drain		D	
2	D	drain			
3	G	gate		G (T	
4	S	source	3 Transparent top view DFN2020MD-6 (SOT1220)	Transparent top view	
5	D	drain			
6	D	drain		S 017aaa259	
7	D	drain			
8	S	source			

3. Ordering information

Table 3. Ordering inf	ormation					
Type number Package						
	Name	Description	Version			
PMPB20XPE	DFN2020MD-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220			

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB20XPE	1D

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions		Min	Max	Unit
drain-source voltage	T _j = 25 °C		-	-20	V
gate-source voltage			-12	12	V
drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-10.3	А
	V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-7.2	А
	V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-4.5	А
peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-30	А
total power dissipation	T _{amb} = 25 °C	[1]	-	1.7	W
	drain-source voltage gate-source voltage drain current peak drain current	$\begin{array}{c} \mbox{drain-source voltage} \\ \mbox{drain source voltage} \\ \mbox{drain current} \\ \end{array} \begin{array}{c} T_{j} = 25 \ ^{\circ}\text{C} \\ \\ \mbox{V}_{GS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 25 \ ^{\circ}\text{C}; \ t \leq 5 \ ^{\circ}\text{S} \\ \\ \mbox{V}_{GS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \\ \mbox{V}_{GS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 100 \ ^{\circ}\text{C} \\ \\ \mbox{V}_{GS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 100 \ ^{\circ}\text{C} \\ \end{array}$	$\begin{array}{c} \mbox{drain-source voltage} \\ \mbox{drain source voltage} \\ \mbox{drain current} \\ \end{array} \begin{array}{c} T_{j} = 25 \ ^{\circ}\text{C} \\ \\ \mbox{T}_{gS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 25 \ ^{\circ}\text{C}; \ t \leq 5 \ ^{\circ}\text{S} \\ \mbox{I1} \\ \hline \\ \mbox{V}_{GS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 25 \ ^{\circ}\text{C} \\ \mbox{I1} \\ \hline \\ \mbox{V}_{GS} = -4.5 \ ^{\circ}\text{V}; \ T_{amb} = 100 \ ^{\circ}\text{C} \\ \mbox{I1} \\ \hline \\ \mbox{peak drain current} \\ \end{array} \begin{array}{c} \mbox{In current} \\ In current$	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	drain-source voltage $T_j = 25 \degree C$ - -20 gate-source voltage -12 12 drain current $V_{GS} = -4.5 \lor; T_{amb} = 25 \degree C; t \le 5 \$$ [1] - -10.3 $V_{GS} = -4.5 \lor; T_{amb} = 25 \degree C; t \le 5 \$$ [1] - -7.2 $V_{GS} = -4.5 \lor; T_{amb} = 100 \degree C$ [1] - -4.5 peak drain current $T_{amb} = 25 \degree C; single pulse; t_p \le 10 \ \mu s$ - -30

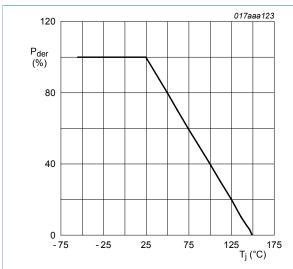
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Symbol	Parameter	Conditions		Min	Мах	Unit
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.5	W
		T _{sp} = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode		,			,
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.9	А
ESD maxim	num rating	1				
V _{ESD}	electrostatic discharge voltage	НВМ	[2]	-	2400	V

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
 Measured between all pins.





$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

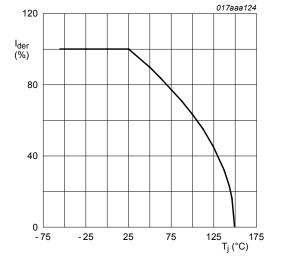
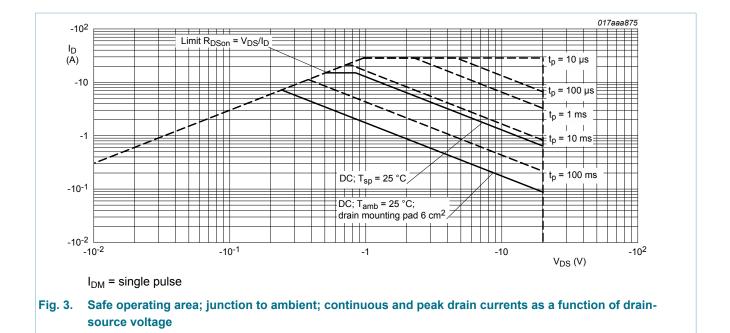


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^*C)}} \times 100\%$$

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6. Thermal characteristics

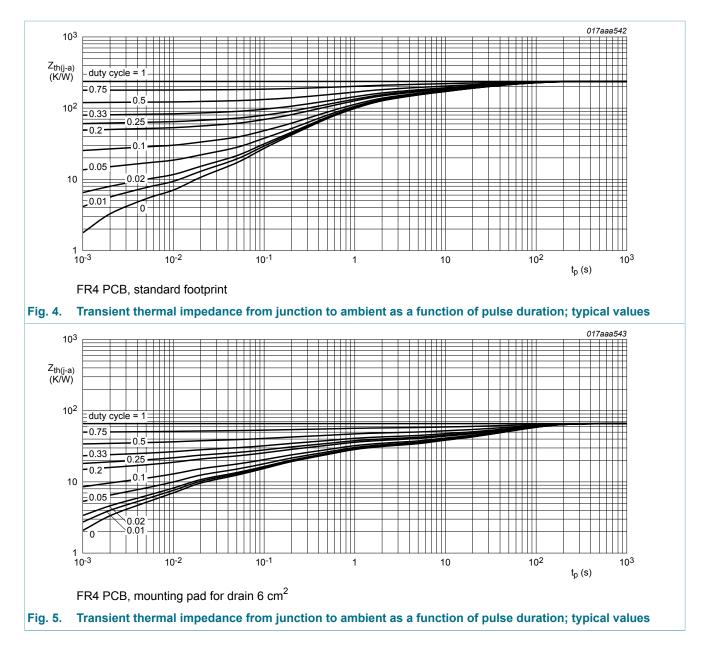
Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1]	-	235	270	K/W
	-	[2]	-	67	74	K/W	
	ampient	in free air; t ≤ 5 s	[2]	-	33	36	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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7. Characteristics

Table 7. Ch	aracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 μA; V _{DS} = V _{GS} ; T _j = 25 °C	-0.47	-0.68	-0.9	V
I _{DSS}	drain leakage current	V_{DS} = -20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
R _{DSon}	drain-source on-state	V_{GS} = -4.5 V; I _D = -7.2 A; T _j = 25 °C	-	19	23.5	mΩ
	resistance	V _{GS} = -4.5 V; I _D = -7.2 A; T _j = 150 °C	-	27	33	mΩ
		V _{GS} = -2.5 V; I _D = -6.4 A; T _j = 25 °C	-	22	29	mΩ
		V _{GS} = -1.8 V; I _D = -3.7 A; T _j = 25 °C	-	28	39	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -7.2 A; T _j = 25 °C	-	50	-	S
R _G	gate resistance	f = 1 MHz	-	5.2	-	Ω
Dynamic cl	naracteristics		I	I		
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -7.2 A; V _{GS} = -4.5 V;	-	30	45	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	4.1	-	nC
Q _{GD}	gate-drain charge		-	7.1	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	2945	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	245	-	pF
C _{rss}	reverse transfer capacitance		-	210	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -7.2 A; V _{GS} = -4.5 V;	-	13	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	60	-	ns
t _{d(off)}	turn-off delay time		-	92	-	ns
t _f	fall time		-	50	-	ns

Source-drain diode

source-drain voltage

 V_{SD}

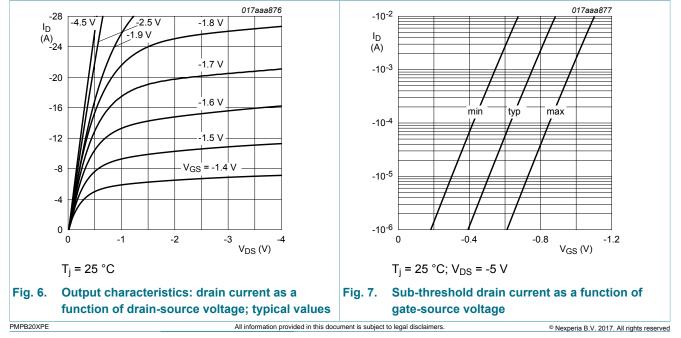
I_S = -1.9 A; V_{GS} = 0 V; T_j = 25 °C

-1.2

V

-0.7

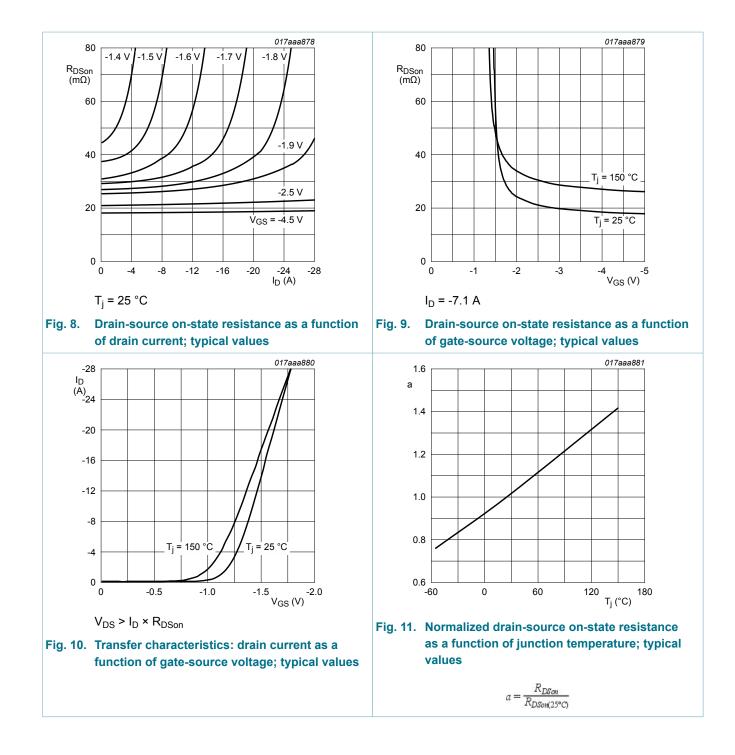
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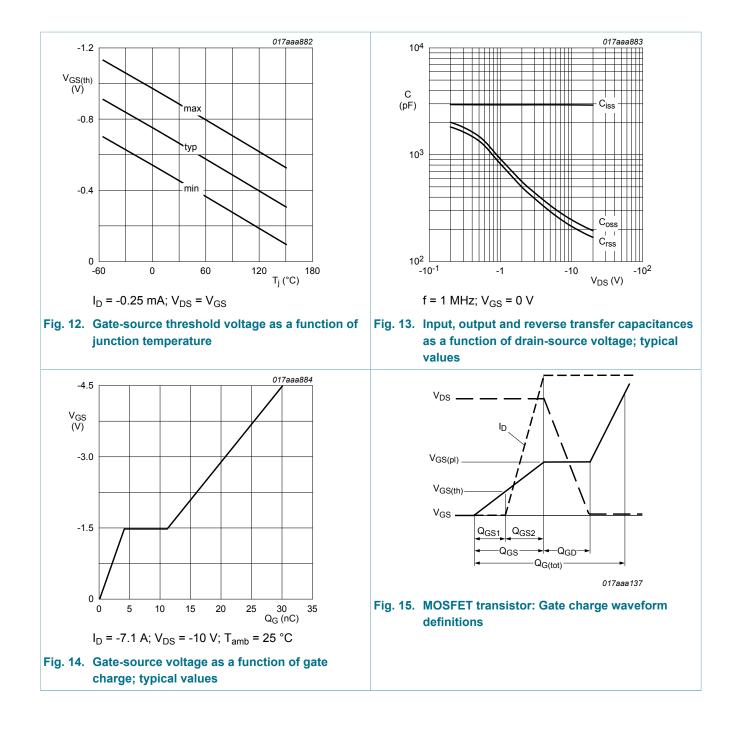


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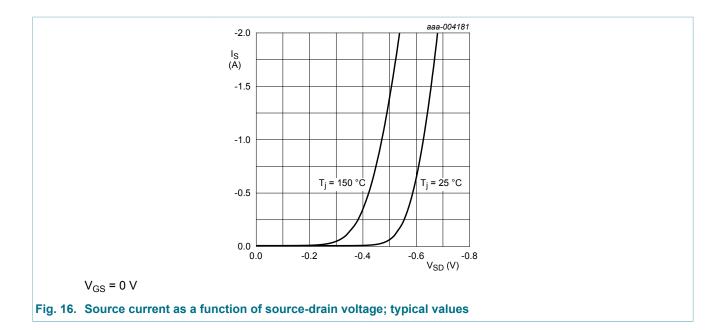
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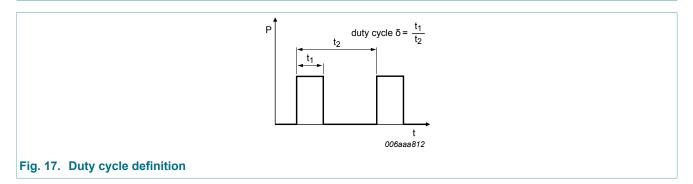


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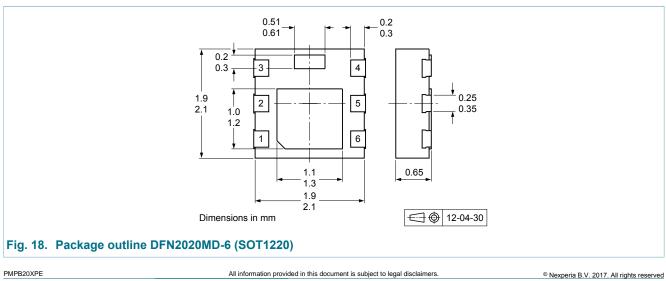
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8. Test information



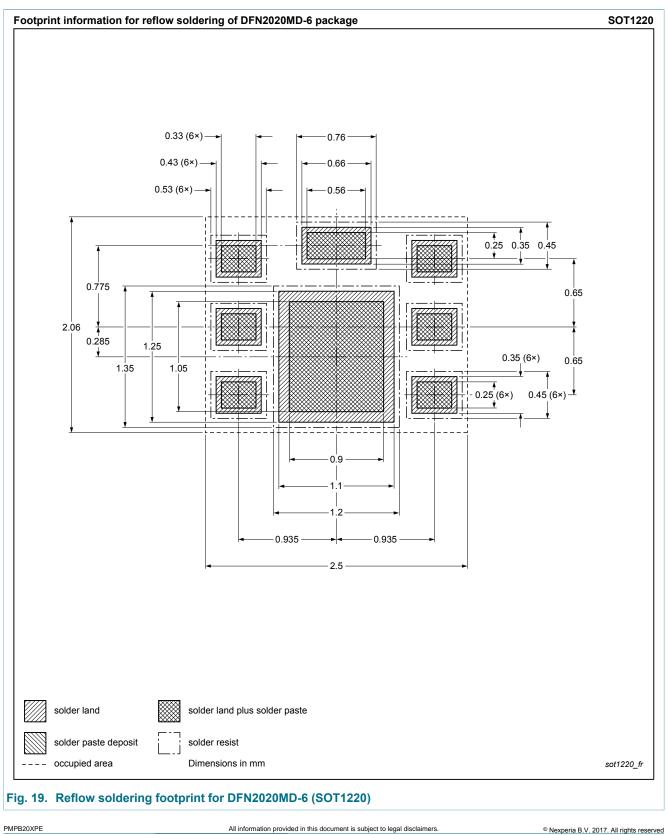
9. Package outline



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10. Soldering



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11. Revision history

Table 8. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMPB20XPE v.1	20121130	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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